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# Novel $SrLaAlO_4$ : $Mn^{4+}$ deep-red emitting phosphors with excellent responsiveness to phytochrome $P_{FR}$ for plant cultivation LEDs: synthesis, photoluminescence properties, and thermal stability

K. Sankarasubramanian, <sup>a</sup> Balaji Devakumar, <sup>a</sup> G. Annadurai, <sup>a</sup> Liangling Sun, <sup>a</sup> Yu-Jia Zeng \*\* and Xiaoyong Huang \*\* and Xiaoyong Huang \*\*.

Herein, novel rare-earth-free  $\mathrm{Mn^{4+}}$ -doped  $\mathrm{SrLaAlO_4}$  deep-red emitting phosphors were successfully synthesized via a traditional solid-state reaction method. The crystal structure and phase purity of the asprepared samples were confirmed by XRD Rietveld refinement. Photoluminescence properties of SrLaAlO<sub>4</sub>:Mn<sup>4+</sup> phosphors were examined in detail using photoluminescence spectra, decay lifetimes, temperature-dependent emission spectra and internal quantum efficiency measurements. The excitation spectrum obtained by monitoring at 730 nm contained two excitation bands centered at 364 and 520 nm within the range of 200–550 nm due to the Mn<sup>4+</sup>– $O^{2-}$  charge-transfer band and the  $^4A_{2q} \rightarrow$  $^{4}$ T<sub>1 $\alpha$ </sub>,  $^{4}$ T<sub>2 $\alpha$ </sub> transitions of the Mn<sup>4+</sup> ions. Under the 364 nm excitation, the SrLaAlO<sub>4</sub>:Mn<sup>4+</sup> phosphors exhibited an intense deep-red emission band in 610-790 nm wavelength range peaking at 730 nm, which was assigned to the  ${}^{2}E_{q} \rightarrow {}^{4}A_{2q}$  transition of Mn<sup>4+</sup> ions. The deep red emission showed excellent responsiveness to phytochrome PFR, revealing that the SrLaAlO<sub>4</sub>:0.4% Mn<sup>4+</sup> phosphors possessed a possible application in deep-red light-emitting diodes (LEDs) for plant cultivation. The optimal doping concentration of  $Mn^{4+}$  ions was found to be 0.4 mol%. The critical distance  $R_c$  for energy transfer among Mn<sup>4+</sup> ions was determined to be 5.86 Å and the concentration quenching mechanism was confirmed to be the electric dipole-dipole interaction. In addition, the Commission International de l'Eclairage (CIE) colour coordinates of the SrLaAlO<sub>4</sub>:0.4% Mn<sup>4+</sup> phosphors (0.734, 0.266) were located in the deep red region and the corresponding internal quantum efficiency was measured to be about 29%. The above results confirmed that the as-prepared SrLaAlO<sub>4</sub>:0.4% Mn<sup>4+</sup> deep red emitting phosphors might be a potential candidate for plant cultivation LEDs.

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## Introduction

Inorganic phosphors with outstanding optical properties have been broadly used over the past decades in many applications, such as, solid-state lighting, displays, optical temperature sensors, solar cells, and plant cultivation. <sup>1-15</sup> Currently, lightemitting diodes (LEDs) are used as light sources for indoor plant cultivation in the agricultural area, which leads to improved plant cultivation within a natural atmosphere (*e.g.*, light, water, air, temperature, and growth media). <sup>16-18</sup> Artificial light sources are important for indoor plant cultivation to enhance the growth of plant tissues. The absorption spectra of

photosynthesis pigments like chlorophyll and carotenoid match well with the light sources of blue and red LEDs. It has been reported that blue light with the wavelength of 410–500 nm affects the growth of chlorophyll, leaf morphogenesis, flower-bud formation, stomatal opening, and phototropism, and red light with the wavelength of 610–700 nm may be supportive to develop the vegetative flowering, budding, and internodal elongation, while the far-red light around 730 nm promotes the plant cultivation and photosynthesis. <sup>19-22</sup> Hence, it is essential to find alternative high colour purity red or deep red emitting phosphors.

Eu<sup>3+</sup> and Sm<sup>3+</sup> doped red phosphors are widely used in many fields, but their limitations in LEDs applications are mainly due to their sharp absorption peaks in ultraviolet (UV) and blue regions; and moreover, most of rare earth ions are costly. In addition, Eu<sup>2+</sup> doped oxynitrides and nitrides based red phosphors also have some unavoidable deficiencies in practical applications caused by their critical synthesis process, because

<sup>&</sup>lt;sup>a</sup>Key Lab of Advanced Transducers and Intelligent Control System, Ministry of Education and Shanxi Province, College of Physics and Optoelectronics, Taiyuan University of Technology, Taiyuan 030024, P. R. China. E-mail: huangxy04@126.com 
<sup>b</sup>Shenzhen Key Laboratory of Laser Engineering, College of Optoelectronic Engineering, Shenzhen University, Shenzhen 518060, P. R. China. E-mail: yjzeng@szu.edu.cn

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high temperature and high pressure are needed for their preparation.23-27 In recent years, many researchers intended to find eco-friendly non-rare-earth ions activated red-emitting phosphors. Compared with Eu3+ and Sm3+ doped red phosphors, Mn<sup>4+</sup> ions activated phosphors show several important advantages, such as strong excitation peak at 300 to 480 nm and strong emission in the range from 600 to 780 nm, economically cheap and no absorption in green spectral range. 12,28-32 Mn4+ ions could be suitable activators for replacing the Al<sup>3+</sup>, Ti<sup>4+</sup>, Zr<sup>4+</sup>, Si<sup>4+</sup> or Ge<sup>4+</sup> sites in the host materials and give rise to red or deep red emissions originating from spin-forbidden  ${}^{2}E_{g} \rightarrow {}^{4}A_{2g}$ transition of Mn<sup>4+</sup> ions. The Mn<sup>4+</sup> activated fluorides usually display red emissions around 620-640 nm because of their weak hybridization effect. In sharp contrast, Mn4+ activated oxide materials generally exhibit deep-red emissions with wavelengths longer than 650 nm owing to their strong hybridization effect. In recent years, many researchers investigated the Mn<sup>4+</sup> activated oxide-based phosphors due to their chemical stability and eco-friendly synthesis process.33-46

In this work, we reported on novel deep red emitting Mn<sup>4+</sup>activated SrLaAlO<sub>4</sub> phosphors prepared by using conventional high-temperature solid-state reaction method. The crystal structure, morphology, and luminescence properties of SrLaAlO4:-Mn<sup>4+</sup> phosphors were investigated in detail. The SrLaAlO<sub>4</sub> compound crystallizes in tetragonal structure with the space group of I4/mmm. In SrLaAlO<sub>4</sub> host, Al<sup>3+</sup> ion is octahedrally coordinated with six oxygens, and thus Mn<sup>4+</sup> ions would occupy Al<sup>3+</sup> sites in SrLaAlO<sub>4</sub> host lattice due to their close ionic radii. Under 364 nm near-UV excitation, the SrLaAlO<sub>4</sub>:Mn<sup>4+</sup> phosphors exhibited deep red emission in the 650-800 nm wavelength range peaking at 730 nm, which matched well with the absorption spectra of phytochrome P<sub>FR</sub>. The optimal doping concentration of Mn<sup>4+</sup> ions was 0.4 mol%, and the corresponding internal quantum efficiency (IQE) of the SrLaAlO<sub>4</sub>:0.4% Mn<sup>4+</sup> phosphor was found to be about 29%. Finally, a deep-red LED device was fabricated by coating the as-prepared SrLaAlO<sub>4</sub>:0.4% Mn<sup>4+</sup> phosphors on the surface of a 365 nm InGaN LED chip. The results demonstrated the SrLaAlO<sub>4</sub>:Mn<sup>4+</sup> phosphors could be new non-rare-earth-based red emitting luminescence materials for applications in plant cultivation LEDs.

# **Experimental**

The SrLaAl<sub>1-x</sub>O<sub>4</sub>:xMn<sup>4+</sup> (abbreviated as SLA:xMn<sup>4+</sup>: x = 0.1%, 0.2%, 0.4%, 0.6%, 0.8% and 1%) phosphors with various Mn<sup>4+</sup> doping concentrations were prepared via solid-state reaction method. The SrCO<sub>3</sub> (analytical reagent, A.R.), La<sub>2</sub>O<sub>3</sub> (99.99%), Al<sub>2</sub>O<sub>3</sub> (A.R.), and MnCO<sub>3</sub> (A.R.) were used as the source materials of Sr, La, Al and Mn, respectively. According to the stoichiometric ratio, the SrCO<sub>3</sub>, La<sub>2</sub>O<sub>3</sub>, Al<sub>2</sub>O<sub>3</sub> and MnCO<sub>3</sub> were weighed and the mixture was ground thoroughly using an agate mortar. Then, this uniform mixture was placed in an alumina crucible and sintered at 1500 °C for 6 h in air atmosphere. Finally, the product was allowed to cool down to room temperature, and re-ground for further characterization.

The crystal system of SLA:Mn<sup>4+</sup> phosphors were characterized using powder X-ray diffraction (XRD) pattern (Bruker D8

Advance, CuKα radiation). Rietveld refinement of the prepared sample was performed by the FULLPROF software. The surface morphological and elemental mapping of the SLA:0.4% Mn<sup>4+</sup> phosphors were performed using a field-emission scanning electron microscope (FE-SEM; MAIA3 TESCAN). The roomtemperature photoluminescence (PL) and photoluminescence excitation (PLE) as well as decay curves were recorded using Edinburgh FS5 spectrofluorometer equipped with a 150 W continuous-wavelength xenon lamp and a pulsed xenon lamp as the excitation source, respectively. The IQE measurement was achieved by using Edinburgh FS5 spectrofluorometer equipped with an integrating sphere coated with barium sulphate. The temperature-dependent emission spectra were measured by using Edinburgh FS5 spectrofluorometer in the range of 303-483 K and the temperature was tuned by the temperature controlling system.

## Results and discussion

The phase purity and crystalline nature of the as-prepared SLA:0.4% Mn<sup>4+</sup> phosphors were examined using XRD. Fig. 1 shows the XRD patterns of pure SLA and 0.4% Mn<sup>4+</sup> doped SLA phosphors. It can be seen that all diffraction peaks matched well with standard data of SLA (JCPDS card 24-1125), which belongs to the tetragonal crystal system. 47 Any other crystalline phase was not observed after the doping of Mn<sup>4+</sup> ions. The inclusion of Mn4+ ion into the SLA lattice did not induce any significant change on the crystal system of the host because of their similar valence and ionic radii of  $Al^{3+}$  (r = 0.535 Å) and  $\mathrm{Mn}^{4+}$  (r = 0.530 Å) ions. The radius percentage value of SLA:0.4% Mn<sup>4+</sup> phosphors was calculated using the formula:50

$$D_{\rm r} = \frac{R_{\rm m}({\rm CN}) - R_{\rm d}({\rm CN})}{R_{\rm m}({\rm CN})} \times 100\%$$
 (1)

where D<sub>r</sub> radius percentage difference and CN denotes coordination number,  $R_{\rm m}$  and  $R_{\rm d}$  represent the ionic radii of host

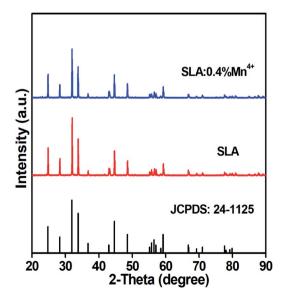


Fig. 1 XRD patterns of pure SLA and 0.4% Mn<sup>4+</sup> doped SLA phosphors.

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cation and doped ion, respectively. The radius percentage value of Al<sup>3+</sup>/Mn<sup>4+</sup> was 0.9%, which was smaller than 30%. Furthermore, an acceptable percentage difference in ionic radii between doped and substituted ions must not exceed 30%, which means that it is possible for Mn<sup>4+</sup> ion enter into the Al<sup>3+</sup> sites due to the similar radius (Mn<sup>4+</sup> and Al<sup>3+</sup>). It is impracticable for Mn<sup>4+</sup> ions to substitute La<sup>3+</sup> due to the large difference between the ionic radii of Mn<sup>4+</sup> (r = 0.530 Å) and La<sup>3+</sup> (r = 1.032Å).51

Fig. 2(a) shows the observed (black rounds), calculated (solid line), and different (bottom) XRD profiles for the Rietveld refinement of SLA:0.4% Mn4+ phosphors. From the XRD pattern, all the diffraction peaks were effectively indexed by tetragonal crystal system with the space group of I4/mmm. For SLA:0.4% Mn<sup>4+</sup> phosphors, the lattice parameter values were calculated to be a = b = 3.75545 Å, c = 12.63941 Å and V =178.258  $\text{Å}^3$  and the refinement finally converged to  $R_p = 8.97\%$ and  $R_{\rm wp} = 11.34\%$ , indicating the refined atom, peak position and fraction factors obeyed the reflection conditions. Fig. 2(b) shows the schematic diagram of the SLA:0.4% Mn<sup>4+</sup> structure in tetragonal crystal system, in which Sr or Al atoms are coordinated by six O atoms, belonging to octahedral symmetry.

Fig. 3(a) represents the FE-SEM image of the SLA:0.4% Mn<sup>4+</sup> phosphors. The particles were aggregated with irregular morphology. Approximately the size of the particles was in micrometer range. Meanwhile, the elemental mapping result confirmed that the Sr, La, Al, O and Mn elements were uniformly distributed throughout the particles, as indicated in Fig. 3(b-f).

Fig. 4(a) shows the PLE and PL spectra of SLA:0.4% Mn<sup>4+</sup> phosphors. The PLE spectrum monitored at 730 nm contained two broad excitation bands in the range of 250-550 nm, which could be well fitted by Gaussian peaks centered at 335, 381, 455 and 519 nm corresponding to the Mn<sup>4+</sup>-O<sup>2-</sup> charge transfer band, the  $^4A_{2g} \rightarrow \,^4T_{1g},\,^4A_{2g} \rightarrow \,^2T_{2g}$  and  $^4A_{2g} \rightarrow \,^4T_{2g}$  transitions of Mn<sup>4+</sup> ions. Under the 364 nm excitation, the obtained PL spectrum showed an intense emission band in the deep red range of 650-800 nm peaking at 730 nm, corresponding to the  $^{2}\mathrm{E_{g}} \rightarrow ^{4}\mathrm{A_{2g}}$  vibronic transition of Mn $^{4+}$  ions. $^{52,53}$  In Fig. 4(b), the

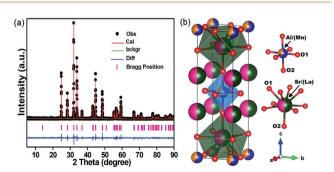


Fig. 2 (a) Rietveld refinement XRD patterns of SLA:0.4% Mn<sup>4+</sup> phosphors by the FULLPROF program. The solid black rounds, red lines and blue lines express the observed and calculated XRD patterns of the sample as well as their differences. The short vertical pink lines display the positions of Bragg reflection. (b) Schematic crystal structure of SLA: 0.4% Mn<sup>4+</sup> phosphors

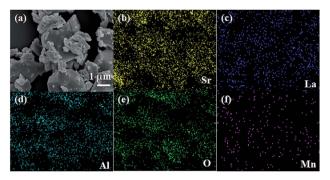


Fig. 3 (a) FE-SEM image and (b-f) elemental mapping of SLA:0.4% Mn<sup>4+</sup> phosphors.

PL spectrum of SLA:0.4% Mn<sup>4+</sup> phosphors was compared with the absorption spectra of phytochrome P<sub>R</sub> and P<sub>FR</sub>. The absorption spectrum of phytochrome  $P_{FR}$  was centered at about 730 nm. Obviously a considerable overlap was found between the emission spectrum of SLA:0.4% Mn<sup>4+</sup> phosphors and the absorption spectrum of phytochrome PFR, which confirmed that the SLA:0.4% Mn<sup>4+</sup> phosphor might be used for indoor plant cultivation as far-red emitting light source.

Fig. 5(a) shows the room-temperature PL spectra of SLA:xMn<sup>4+</sup> phosphors with different Mn<sup>4+</sup> concentrations under the excitation of 364 nm. It can be examined that all the emission peak positions and shapes have no noticeable change with altering Mn<sup>4+</sup> ion concentration except the intensity. Fig. 5(b) shows the PL intensity as a function of Mn<sup>4+</sup> doping concentration in SLA:xMn<sup>4+</sup> phosphors. It was obvious that, the PL intensity of Mn4+ increased at first, until it reached the maximum at x = 0.4%, then it decreased slowly with increasing doping concentration, which was attributed to the concentration quenching effect. The decrease in PL intensity with increasing Mn4+ doping concentration may be due to the increase in nonradioactive decay, which was more possible beyond the optimal doping concentration. It has identified that the energy transfer is inversely proportional to  $R_n$ , where R is the distance between the neighbouring Mn<sup>4+</sup> ions, and then the R<sub>c</sub> could be calculated from the concentration quenching data. The  $R_c$  between Mn<sup>4+</sup> ions can be calculated using the following formula:54

$$R_{\rm c} \approx 2 \left(\frac{3V}{4\pi x_{\rm c} Z}\right)^{1/3} \tag{2}$$

where  $R_c$  is the critical distance, V is the volume of the unit cell,  $x_c$ refers to the critical doping concentration and Z is the number of sites available for the dopant in the unit cell. Herein,  $x_c = 0.4\%$ ; V = 178.258 Å<sup>3</sup>; and Z = 6. Therefore, the  $R_c$  value of phosphors was calculated to be about 35.48 Å. This  $R_c$  value of Mn<sup>4+</sup> doped SLA was higher than 5 Å, so that the exchange interaction mechanism was impossible between the Mn4+ ion. Therefore, the concentration quenching was mostly influenced by the electric multipolar interaction among Mn4+ ions as follows:

$$\frac{I}{x} = k \left[ 1 + \beta(x)^{\theta/3} \right]^{-1} \tag{3}$$

where I is the emission intensity; x is concentration of  $Mn^{4+}$ ions; k and  $\beta$  are constants for the given host;  $\theta$  is a function of

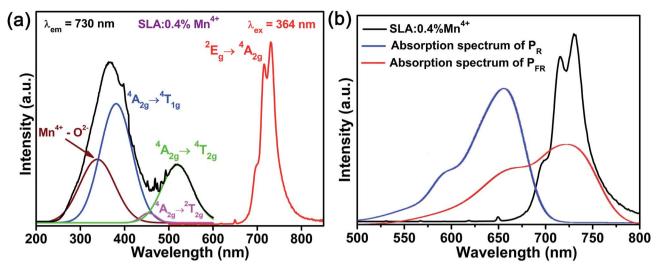


Fig. 4 (a) Room-temperature PLE and PL spectra of SLA:  $0.4\% \, \text{Mm}^{4+}$  phosphors. (b) PL spectrum of SLA:  $0.4\% \, \text{Mm}^{4+}$  phosphors and the absorption spectra of phytochrome  $P_{FR}$  and  $P_{R}$ .

multipolar interaction, where  $\theta = 6$ , 8 and 10 stands for the dipole–dipole (d–d), dipole–quadrupole (d–q), quadrupole–quadrupole (q–q) interactions, respectively.<sup>55</sup> Fig. 5(c) elucidates

the relationship between  $\log(x)$  *versus*  $\log(I/x)$ , which can be well fitted by a straight line with a slope of -1.89. Hence, the  $\theta$  value was calculated to be 5.67, which was close to 6. Thus the

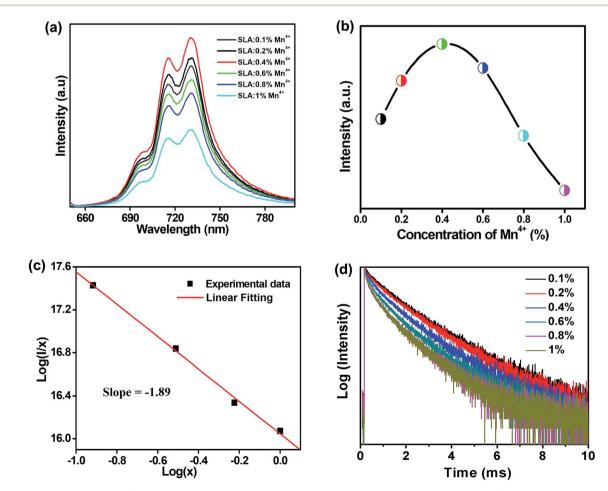


Fig. 5 (a) PL spectra of SLA: $xMn^{4+}$  (x = 0.1%, 0.2%, 0.4%, 0.6%, 0.8%, and 1%) phosphors as a function of  $Mn^{4+}$  doping concentrations. (b) PL emission intensities with  $Mn^{4+}$  doping concentration. (c) The relationship between log(I/x) versus log(x). (d) PL decay curves and calculated lifetime values of SLA:0.4%  $Mn^{4+}$  phosphors under the excitation of 364 nm and monitored at 730 nm.

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concentration quenching mechanism was dominant by the d-d interaction in SLA:Mn<sup>4+</sup> phosphors.

Fig. 5(d) shows the concentration-dependent PL decay curves of SLA:xMn<sup>4+</sup>(x = 0.1%, 0.2%, 0.4%, 0.6%, 0.8%, and 1%) phosphors monitored at 730 nm under the excitation of 364 nm. The PL decay curves were fitted by a single exponential decay equation:

$$I(t) = I_0 + A \exp(-t/\tau) \tag{4}$$

where I(t) is the emission intensities at t,  $I_0$  represents the initial emission intensities,  $\tau$  is the lifetime and A is the constant. The estimated lifetime values were about 1.65, 1.35, 1.19, 1.08, 0.96, and 0.92 ms for various Mn<sup>4+</sup> concentrations of x=0.1%, 0.2%, 0.4%, 0.6%, 0.8% and 1%, respectively. The values of decay lifetime of SLA:xMn<sup>4+</sup> phosphors decreased with increasing of Mn<sup>4+</sup> doping concentrations. The decrease of lifetime values may be due to the decrease in distance between Mn<sup>4+</sup> ions with increase of Mn<sup>4+</sup> concentration, the enhanced possibility of more frequent energy transfer between Mn<sup>4+</sup> ions with increasing of Mn<sup>4+</sup> concentration and the increase in non-radioactive transition probability. <sup>56–58</sup>

CIE coordinates are very essential to reveal that the exact emission and colour purity of the sample. Fig. 6 illustrates the CIE chromaticity diagram of SLA:0.4%  $\rm Mn^{4+}$  phosphors with the excitation of 364 nm. The CIE coordinate values of the SLA:0.4%  $\rm Mn^{4+}$  phosphors were calculated to be (0.734, 0.266), which located in the deep red region. The inset of Fig. 6 shows the digital image of the SLA:0.4%  $\rm Mn^{4+}$  phosphors under the excitation of 365 nm UV-lamp.

IQE value of SLA:0.4% Mn<sup>4+</sup> phosphors with the excitation of 364 nm was measured using an integrating sphere. The IQE value can be calculated using the following equation:<sup>59</sup>

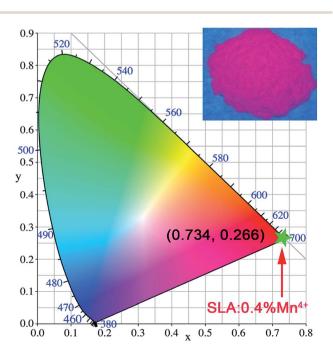


Fig. 6 CIE chromaticity coordinates of SLA:0.4%  $\rm Mn^{4+}$  phosphors ( $\lambda_{\rm ex}$  = 364 nm). Inset shows the image of SLA:0.4%  $\rm Mn^{4+}$  phosphors under 365 nm UV lamp.

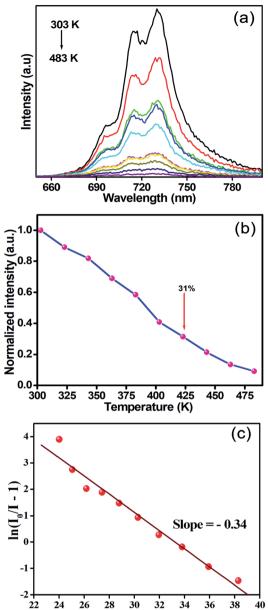


Fig. 7 (a) Temperature dependent PL spectra of SLA:0.4%  $\rm Mn^{4+}$  phosphors ( $\lambda_{\rm ex}=364$  nm). (b) Normalized PL intensity of SLA:0.4%  $\rm Mn^{4+}$  phosphors as a function of various temperatures. (c) The relationship of  $\rm ln(\it l_0/\it l-1)$  versus  $\rm 1/\it kT$  of the SLA:0.4%  $\rm Mn^{4+}$  phosphors.

1/kT

$$\eta_{\rm QE} = \frac{\int L_{\rm S}}{\int E_{\rm R} - \int E_{\rm S}} \tag{5}$$

where  $L_{\rm S}$ ,  $E_{\rm S}$  and  $E_{\rm R}$  are the luminescence emission spectrum of the sample, spectrum of the light used for exciting the sample and spectrum of the excitation light without the sample, respectively. The IQE value of the SLA:0.4% Mn<sup>4+</sup> phosphors was measured to be 29% under the excitation of 364 nm, which was higher than that of Ca<sub>14</sub>Al<sub>10</sub>O<sub>35</sub>:Mn<sup>4+</sup> (IQE: 19.4%),<sup>60</sup> (NH<sub>4</sub>)<sub>2</sub>TiF<sub>6</sub>:Mn<sup>4+</sup> (IQE: 16.4%),<sup>61</sup> and CaMg<sub>2</sub>Al<sub>16</sub>O<sub>27</sub> (IQE: 16%) phosphors,<sup>33</sup> but smaller than some oxide and fluoride phosphors like Ca<sub>2</sub>YSbO<sub>6</sub>:Mn<sup>4+</sup> (IQE: 62.6%),<sup>62</sup> and Rb<sub>2</sub>SiF<sub>6</sub>:Mn<sup>4+</sup> (IQE: >90%).<sup>63</sup>

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The thermal behaviour is an important parameter for phosphors in practical application. Fig. 7(a) shows the temperature-dependent PL spectra of SLA:0.4% Mn4+ deep red emitting phosphors recorded at various temperatures in the range of 303-483 K under the excitation of 364 nm. Clearly, the PL intensity decreased with increasing of temperature due to the thermal quenching effect. Fig. 7(b) shows the normalized PL intensity of SLA:0.4% Mn<sup>4+</sup> phosphors as a function of various temperatures. It can be clearly seen that the PL intensity at the temperature of 423 K was found to be about 31% of that at 303 K, which was better than the reported value of 27% of Gd<sub>2</sub>-ZnTiO<sub>6</sub>:Mn<sup>4+</sup> phosphors.<sup>64</sup> Furthermore, considerable changes were not found in their spectra, which indicated that the asprepared SLA:Mn4+ phosphors offered low thermal stability due to its charge compensation-related defects induced by the replacement of Mn4+ ion into Al3+ host site (not stable at temperatures above 250 K). The activation energy was calculated using Arrhenius equation, which can be explained below as:65

$$I(T) = \frac{I_0}{1 + c \exp\left(-\frac{\Delta E_a}{kT}\right)} \tag{6}$$

where  $I_0$  is the emission intensity at the initial temperature; I(T)is the emission intensity at measured temperature; c is a constant; k is the Boltzmann's constant; and  $\Delta E_a$  is the activation energy. Fig. 7(c) demonstrates the plot of  $\ln(I_0/I - 1)$ versus 1/kT. The experimental values were well linearly fitted with a slope of -0.34, and thus the activation energy value was

A deep red emitting LED device was fabricated by using SLA:0.4% Mn<sup>4+</sup> phosphors combined with a 365 nm emitting InGaN LED chip. The electroluminescence (EL) spectrum of asprepared LED device under 20 mA and 3.17 V was shown in Fig. 8. A strong red emission peak at 730 nm in the wavelength

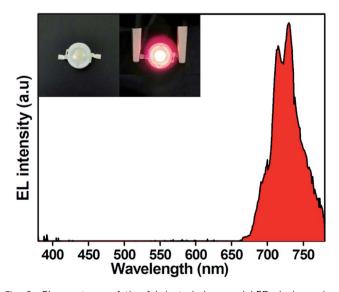


Fig. 8 EL spectrum of the fabricated deep-red LED device using SLA:0.4% Mn<sup>4+</sup> phosphors and a 365 nm near-UV LED chip under a current of 20 mA. Inset shows the fabricated LED device and corresponding luminescent image.

range of 650-800 nm was observed. The luminous efficacy value of the as-fabricated LED device was 0.09 lm W<sup>-1</sup>. The low luminous efficacy may be attributed to the presence of strong emission peak displayed by SLA:0.4% Mn4+ phosphors in the deep red spectral region, where the human eye sensitivity is very low. However, the plants are sensitive in the deep red light. Therefore, the SLA:0.4% Mn4+ phosphors could be used to fabricate deep red-emitting LEDs towards indoor plant cultivation.

### Conclusions

In conclusion, we have successfully synthesized deep red emitting SLA:0.4% Mn4+ phosphors using conventional hightemperature solid-state reaction method. The role of Mn<sup>4+</sup> ions on crystal structure and photoluminescence properties of SLA phosphors was systematically investigated. XRD and Rietveld refinement data proved that the SLA:0.4% Mn<sup>4+</sup> phosphors were indexed by tetragonal crystal system. The SLA:0.4% Mn4+ phosphors exhibited deep red emission peaking at 730 nm under the excitation of 364 nm, and the resultant CIE coordinate values were (0.734, 0.266). The critical energy transfer distance of these phosphors was calculated to be 35.48 Å and the concentration quenching mechanism was confirmed to be the d-d interaction between Mn<sup>4+</sup> ions. Decay lifetime values of SLA:xMn<sup>4+</sup> phosphors gradually decreased with increasing of Mn4+ concentration. Meanwhile, the SLA:0.4% Mn4+ deep red phosphors also exhibited proper thermal stability, in addition, a deep-red LED device was fabricated using a 365 nm InGaN chip combined with the SLA:0.4% Mn4+ red emitting phosphors. The results indicated SLA:0.4% Mn<sup>4+</sup> phosphors would be promising candidate as a deep red phosphor for plant cultivation LEDs applications.

#### Conflicts of interest

There are no conflicts to declare.

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#### Notes and references

- 1 M. Chen, Z. Xia and Q. Liu, J. Mater. Chem. C, 2015, 3, 4197-4204.
- 2 S.-P. Lee, T.-S. Chan and T.-M. Chen, ACS Appl. Mater. Interfaces, 2014, 7, 40-44.
- 3 R. Cao, D. Peng, H. Xu, S. Jiang, Z. Luo, H. Ao and P. Liu, J. Lumin., 2016, 178, 388-391.
- 4 N. Zhang, C. Guo, L. Yin, J. Zhang and M. Wu, J. Alloys Compd., 2015, 635, 66-72.

- 5 X. Huang, Nat. Photonics, 2014, 8, 748-749.
- 6 P. Du, Y. Guo, S. H. Lee and J. S. Yu, *RSC Adv.*, 2017, 7, 3170–3178.
- 7 B. Li, X. Huang, H. Guo and Y. Zeng, *Dyes Pigm.*, 2018, **150**, 67–72.
- 8 X. Huang, J. Alloys Compd., 2017, 690, 356-359.
- 9 X. Huang, B. Li and H. Guo, *J. Alloys Compd.*, 2017, **695**, 2773–2780.
- 10 P. Du, X. Huang and J. S. Yu, *Inorg. Chem. Front.*, 2017, 4, 1987–1995.
- 11 P. Du, X. Huang and J. S. Yu, Chem. Eng. J., 2018, 337, 91-100.
- 12 Q. Sun, S. Wang, B. Li, H. Guo and X. Huang, *J. Lumin.*, 2018, **203**, 371–375.
- 13 X. Huang, S. Wang, B. Li, Q. Sun and H. Guo, *Opt. Lett.*, 2018, 43, 1307–1310.
- 14 X. Huang, B. Li, H. Guo and D. Chen, *Dyes Pigm.*, 2017, **143**, 86–94.
- 15 P. Du, L. Luo, X. Huang and J. S. Yu, *J. Colloid Interface Sci.*, 2018, **514**, 172–181.
- 16 G. Tamulaitis, P. Duchovskis, Z. Bliznikas, K. Breive, R. Ulinskaite, A. Brazaityte, A. Novičkovas and A. Žukauskas, J. Phys. D: Appl. Phys., 2005, 38, 3182–3187.
- 17 M. Olle and A. Viršile, Agric. Food Sci., 2013, 22, 223-234.
- 18 G. D. Massa, H.-H. Kim, R. M. Wheeler and C. A. Mitchell, *HortScience*, 2008, **43**, 1951–1956.
- 19 J. Chen, N. Zhang, C. Guo, F. Pan, X. Zhou, H. Suo, X. Zhao and E. M. Goldys, *ACS Appl. Mater. Interfaces*, 2016, **8**, 20856–20864.
- 20 N. Yeh, T. J. Ding and P. Yeh, Renewable Sustainable Energy Rev., 2015, 51, 55-61.
- 21 C. Koc, G. A. Anderson and A. Kommareddy, *Isr. J. Aquac.*, 2013, **65**, 797–805.
- 22 H. G. Choi, B. Y. Moon and N. J. Kang, *Sci. Hortic.*, 2015, **189**, 22–31.
- 23 C.-W. Yeh, W.-T. Chen, R.-S. Liu, S.-F. Hu, H.-S. Sheu, J.-M. Chen and H. T. Hintzen, *J. Am. Chem. Soc.*, 2012, **134**, 14108–14117.
- 24 X. Zhang, L. Zhou, Q. Pang, J. Shi and M. Gong, *J. Phys. Chem. C*, 2014, **118**, 7591–7598.
- 25 H. Li, R. Zhao, Y. Jia, W. Sun, J. Fu, L. Jiang, S. Zhang, R. Pang and C. Li, ACS Appl. Mater. Interfaces, 2014, 6, 3163–3169.
- 26 X. Huang, H. Guo and B. Li, J. Alloys Compd., 2017, 720, 29-38.
- 27 X. Huang, B. Li, P. Du, H. Guo, R. Cao, J. S. Yu, K. Wang and X. W. Sun, *Dyes Pigm.*, 2018, **151**, 202–210.
- 28 H. Zhu, C. C. Lin, W. Luo, S. Shu, Z. Liu, Y. Liu, J. Kong, E. Ma, Y. Cao, R.-S. Liu and X. Chen, *Nat. Commun.*, 2014, 5, 4312–4317.
- 29 S. Okamoto and H. Yamamoto, *J. Electrochem. Soc.*, 2010, **157**, J59–J63.
- 30 M. Peng, X. Yin, P. A. Tanner, C. Liang, P. Li, Q. Zhang and J. Qiu, J. Am. Ceram. Soc., 2013, 96, 2870–2876.
- 31 Y. Tanabe and S. Sugano, *J. Phys. Soc. Jpn.*, 1954, **9**, 766–779.
- 32 X. Huang, J. Liang, B. Li, L. Sun and J. Lin, *Opt. Lett.*, 2018, 43, 3305–3308.
- 33 B. Wang, H. Lin, J. Xu, H. Chen and Y. Wang, *ACS Appl. Mater. Interfaces*, 2014, **6**, 22905–22913.

- 34 M. Brik, S. Camardello and A. Srivastava, ECS J. Solid State Sci. Technol., 2015, 4, R39–R43.
- 35 S. Zhang, Y. Hu, H. Duan, L. Chen, Y. Fu, G. Ju, T. Wang and M. He, *RSC Adv.*, 2015, 5, 90499–90507.
- 36 R. Cao, W. Luo, Q. Xiong, A. Liang, S. Jiang and Y. Xu, *J. Alloys Compd.*, 2015, **648**, 937–941.
- 37 T. Sasaki, J. Fukushima, Y. Hayashi and H. Takizawa, *Chem. Lett.*, 2014, 43, 1061–1063.
- 38 Y. Zhydachevskii, A. Suchocki, A. Pajączkowska, A. Kłos, A. Szysiak and A. Reszka, *Opt. Mater.*, 2013, 35, 1664–1668.
- 39 S. Adachi, J. Lumin., 2018, 197, 119-130.
- 40 S. Adachi, J. Lumin., 2018, 202, 263-281.
- 41 X. Huang and H. Guo, Dyes Pigm., 2018, 152, 36-42.
- 42 Q. Sun, B. Li, S. Wang, H. Guo and X. Huang, J. Mater. Sci.: Mater. Electron., 2018, 29, 12972–12977.
- 43 J. Liang, L. Sun, B. Devakumar, S. Wang, Q. Sun, H. Guo, B. Li and X. Huang, *RSC Adv.*, 2018, **8**, 27144–27151.
- 44 Q. Sun, S. Wang, B. Devakumar, B. Li, L. Sun, J. Liang and X. Huang, *RSC Adv.*, 2018, **8**, 28538–28545.
- 45 K. Li, H. Lian and R. Van Deun, J. Lumin., 2018, 198, 155-162.
- 46 K. Li, H. Lian and R. Van Deun, *Dalton Trans.*, 2018, 47, 2501–2505.
- 47 B. Liu, L. Li, X. Q. Liu and X. M. Chen, *J. Mater. Chem. C*, 2016, 4, 4684–4691.
- 48 A. Bergstein and W. B. White, *J. Electrochem. Soc.*, 1971, **118**, 1166–1171.
- 49 Y. Pan and G. Liu, Opt. Lett., 2008, 33, 1816-1818.
- 50 Y. Zhang, X. Li, K. Li, H. Lian, M. Shang and J. Lin, ACS Appl. Mater. Interfaces, 2015, 7, 2715–2725.
- 51 H. Y. Jiao and Y. Wang, *Physica B*, 2012, **407**, 2729–2733.
- 52 A. Srivastava and M. Brik, J. Lumin., 2012, 132, 579-584.
- 53 R. Cao, Q. Xiong, W. Luo, D. Wu, X. Fen and X. Yu, *Ceram. Int.*, 2015, 41, 7191–7196.
- 54 G. Blasse, J. Solid State Chem., 1986, 62, 207-211.
- 55 L. Van Uitert, J. Electrochem. Soc., 1967, 114, 1048–1053.
- 56 Z. Xia, H. Liu, X. Li and C. Liu, *Dalton Trans.*, 2013, 42, 16588-16595.
- 57 G. Y. Lee, J. Y. Han, W. B. Im, S. H. Cheong and D. Y. Jeon, *Inorg. Chem.*, 2012, **51**, 10688–10694.
- 58 J. Y. Han, W. B. Im, G.-y. Lee and D. Y. Jeon, *J. Mater. Chem.*, 2012, 22, 8793–8798.
- 59 T. Wei, Q. Ren, X. Wu, X. Shi, B. Wang and Z. Huo, *Opt. Laser Technol.*, 2016, **85**, 7–13.
- 60 L. Li, Y. Pan, Z. Chen, S. Huang and M. Wu, RSC Adv., 2017, 7, 14868–14875.
- 61 L. Xi, Y. Pan, S. Huang and G. Liu, RSC Adv., 2016, **6**, 76251–76258.
- 62 J. Zhong, D. Chen, X. Chen, K. Wang, X. Li, Y. Zhu and Z. Ji, Dalton Trans., 2018, 47, 6528–6537.
- 63 S. Sakurai, T. Nakamura and S. Adachi, ECS J. Solid State Sci. Technol., 2016, 5, R206–R210.
- 64 H. Chen, H. Lin, Q. Huang, F. Huang, J. Xu, B. Wang, Z. Lin, J. Zhou and Y. Wang, J. Mater. Chem. C, 2016, 4, 2374–2381.
- 65 H. Guo, X. Huang and Y. Zeng, J. Alloys Compd., 2018, 741, 300-306.